

3-Phase Bridge Rectifier + IGBT braking chopper

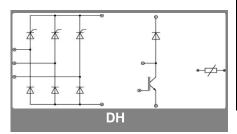
SKDH116/..L105

Features

- Compact design
- Two screws mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- High surge currents
- Up to 1600V reverse voltage
- IGBT Trench4 inside; max Tj=175°C
- CAL4F inside, max Tj=175°C
- $I_{CM}/I_{FM} = 3xI_{C,nom}/I_{F,nom}$ Rectifier diode, max Tj=150°C

Typical Applications*

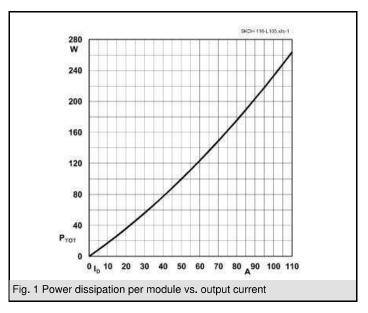
- DC drives
- Controlled filed rectifiers for DC motors
- Controlled battery charger

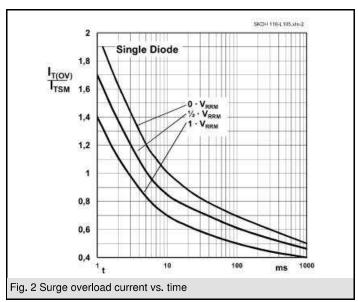


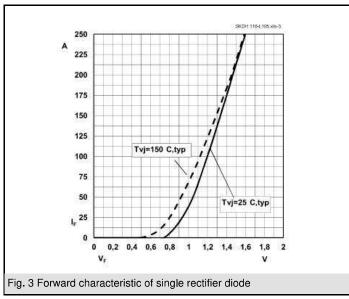
V _{RSM}	V _{RRM} , V _{DRM}	I _D = 110 A (maximum value for continuous operation) (T _c = 80 °C)
1300	1200	(1 _s = 30 G) SKDH116/12-L105
1700	1600	SKDH116/16-L105

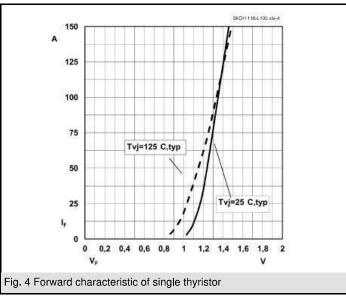
Absolute	Maximum Ratings	T _s = 25 °C, unless otherwise specified				
Symbol	Conditions	Values	Units			
Bridge - Rectifier						
I _D	T _s = 80 °C; inductive load	110	Α			
I _{FSM} /I _{TSM}	$t_p = 10 \text{ ms}; \sin 180; T_{jmax}$	950	Α			
i²t	$t_p = 10 \text{ ms}; \sin 180; T_{jmax}$	4500	A²s			
IGBT - Chopper						
V _{CES} /V _{GES}		1200 / 20	V			
I _C	$T_s = 25 (70) ^{\circ}C$	110 (80)	Α			
I _{CM}	$t_p = 1 \text{ ms}; T_s = {}^{\circ}\text{C}$	315	Α			
Freewheeling - CAL Diode						
V_{RRM}		1200	V			
I _F	$T_s = 25 (70) ^{\circ}C$	90 (60)	Α			
I _{FM}	$t_p = 1 \text{ ms}; T_s = {}^{\circ}\text{C}$	300	Α			
T _{vi}	Diode & IGBT (Thyristor)	- 40 + 175 (-40+ 125)	°C			
T _{stg}		- 40 + 125	°C			
T _{solder}	terminals, 10 s	260	°C			
V _{isol}	a.c. (50) Hz, RMS 1 min. / 1 s	3000 / 3600	V			

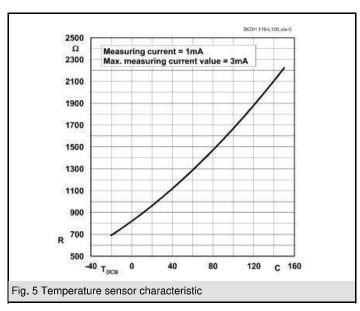
Characteristics		T _s = 25 °C, unless otherwise specified				
Symbol	Conditions	min. typ.	max.	Units		
Diode - Rectifier						
V_{TO} / r_{t}	T _j = 125 °C	0,8 / 7		V / mΩ		
$R_{th(j-s)}$	per diode		1	K/W		
Thyristor - Rectifier						
V _{F(TO)} / r _t	T _i = 125 °C	1,1 / 6		V / mΩ		
R _{th(j-s)}	per Thyristor		0,85	K/W		
I_{GD}	$T_j = 125 ^{\circ}\text{C}; \text{d.c.}$	5		mA		
$V_{ m GT}$ / $I_{ m GT}$	$T_j = 25 ^{\circ}C$		3 / 150	V / mA		
I _H /I∟	$T_j = 25 ^{\circ}\text{C}$	250 / 600		mA		
(dv/dt) _{cr}	T _j = 125 °C		1000	V/µs		
(di/dt) _{cr}	T _j = 125 °C		100	A/µs		
IGBT - Ch	opper					
V _{CE(sat)}	I _C = 105 A, T _j = 25 °C; V _{GE} = 15 V	1,85	2,1	V		
$R_{th(j-s)}$	per IGBT	0,46		K/W		
t _{d(on)} / t _r	valid for all values:	97 / 185		ns		
t _{d(off)} / t _f	V_{CC} = 600 V; V_{GE} = 15 V; I_{C} = 105 A; T_{j} = 150 °C;	443 / 82		ns		
E _{on} +E _{off}	$T_i = 150 ^{\circ}\text{C}; R_G = 3 \Omega;$	47,5		mJ		
	inductive load					
CAL - Dio	de - Freewheeling			•		
$V_{T(TO)} / r_t$	T _i = 150 °C	0,9 / 12,5	1,1 / 13,7	V / mΩ		
R _{th(j-s)}	per diode	0,75		K/W		
I _{RRM}	valid for all values:	22		Α		
Q _{rr}	$I_F = 105 \text{ A; V}_R =600 \text{ V;}$ $dI_F/dt =1700 \text{ A/}\mu\text{s}$	7		μC		
E _{off}	V _{GE} = 0 V; T _j = 150 °C	5,94		mJ		
Temperat	ure Sensor					
R _{TS}	T = 25 (100) °C;	1000 (1670)		Ω		
Mechanical data						
M _S	mounting Torque	2,55	3,45	Nm		

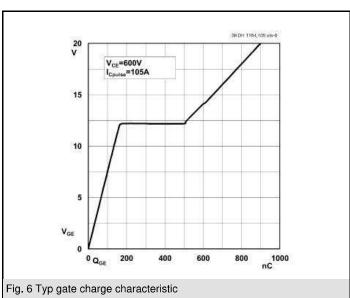


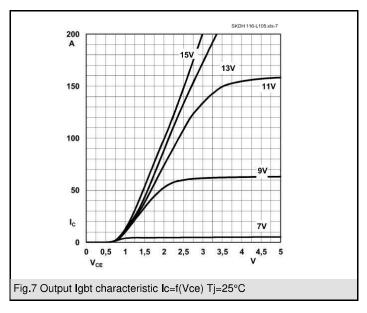


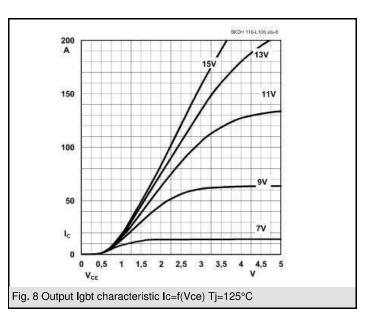


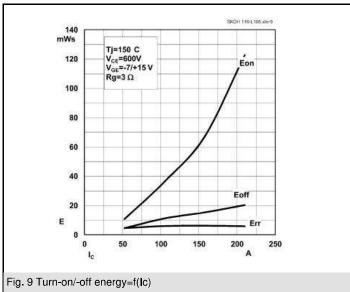


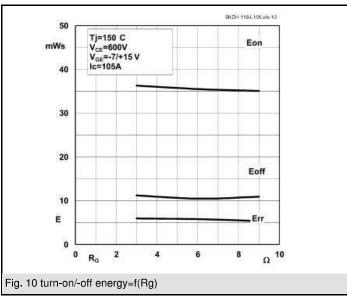


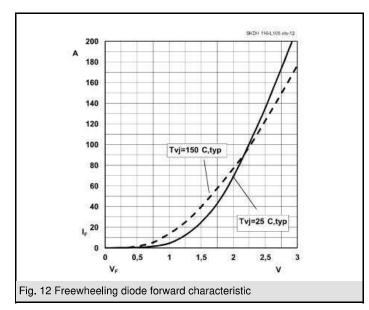


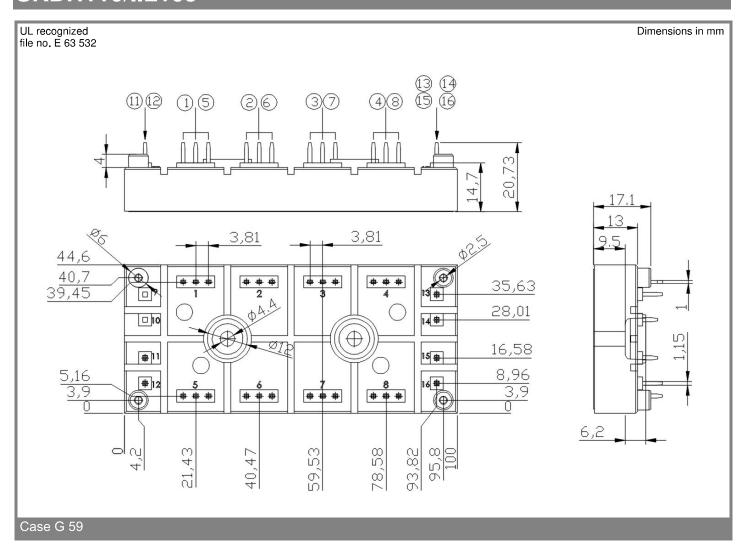


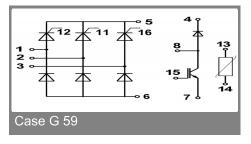












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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